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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/043,010	01/11/2002	Stanford R. Ovshinsky	2076	6131
24963 75	90 02/14/2005	EXAMINER		
ENERGY CONVERSION DEVICES, INC. 2956 WATERVIEW DRIVE			ZERVIGON, RUDY	
ROCHESTER HILLS, MI 48309			ART UNIT	PAPER NUMBER
		·	1763	
			DATE MAILED: 02/14/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

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		Application No.	Applicant(s)			
Office Action Summary		10/043,010	OVSHINSKY, STANFORD R.			
		Examiner	Art Unit			
		Rudy Zervigon	1763			
Period fo	The MAÏLING DATE of this communication a r Reply	ppears on the cover sheet with the	e correspondence address			
THE I - Exter after - If the - If NO - Failui Any r	ORTENED STATUTORY PERIOD FOR REP MAILING DATE OF THIS COMMUNICATION is ions of time may be available under the provisions of 37 CFR 1 SIX (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a reperiod for reply is specified above, the maximum statutory perion to reply within the set or extended period for reply will, by statute ply received by the Office later than three months after the mailed patent term adjustment. See 37 CFR 1.704(b).	I. 1.136(a). In no event, however, may a reply be sply within the statutory minimum of thirty (30) of will apply and will expire SIX (6) MONTHS fruite, cause the application to become ABANDO	days will be considered timely. Tom the mailing date of this communication. The mailing date of this communication. The mailing date of this communication.			
Status						
1)⊠	1) Responsive to communication(s) filed on <u>07 October 2004</u> .					
2a) <u></u> □						
3)	☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
	closed in accordance with the practice under	Ex parte Quayle, 1935 C.D. 11,	453 O.G. 213.			
Dispositi	on of Claims					
4)🖾	4)⊠ Claim(s) <u>1-24</u> is/are pending in the application.					
•	4a) Of the above claim(s) is/are withdrawn from consideration.					
5)	5) Claim(s) is/are allowed.					
-	☑ Claim(s) <u>1-24</u> is/are rejected.					
·	Claim(s) is/are objected to.					
8)	Claim(s) are subject to restriction and	or election requirement.				
Applicati	on Papers					
9)[] :	The specification is objected to by the Examir	ner.				
10)🖾	10)⊠ The drawing(s) filed on <u>11 January 2002</u> is/are: a)□ accepted or b)⊠ objected to by the Examiner.					
	Applicant may not request that any objection to the	* * * * * * * * * * * * * * * * * * * *	, ,			
	Replacement drawing sheet(s) including the corre		· ·			
11)[ <u>X</u> ]	The oath or declaration is objected to by the I	examiner. Note the attached Offi	ce Action or form PTO-152.			
Priority u	nder 35 U.S.C. § 119					
a)[	Acknowledgment is made of a claim for foreignal All b) Some * c) None of:  1. Certified copies of the priority documents.  2. Certified copies of the priority documents.  3. Copies of the certified copies of the priority.	nts have been received. nts have been received in Applic	ation No			
	application from the International Bure	•	Wod III and Haderial Clage			
* See the attached detailed Office action for a list of the certified copies not received.						
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Attachment		_				
	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948)	4) 🔲 Interview Summa Paper No(s)/Mail				
3) 🔲 Infom	e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO-1449 or PTO/SB/06 'No(s)/Mail Date		al Patent Application (PTO-152)			

#### **DETAILED ACTION**

#### Oath/Declaration

1. The oath or declaration is defective. A new oath or declaration in compliance with 37 CFR 1.67(a) identifying this application by application number and filing date is required. See MPEP §§ 602.01 and 602.02.

The oath or declaration is defective because:

There is no oath or declaration present.

## **Drawings**

2. The drawings are objected to under 37 CFR 1.83(a). The drawings must show every feature of the invention specified in the claims. Therefore, the "deposition chamber" must be shown or the feature canceled from the claims. No new matter should be entered.

Corrected drawing sheets in compliance with 37 CFR 1.121(d) are required in reply to the Office action to avoid abandonment of the application. Any amended replacement drawing sheet should include all of the figures appearing on the immediate prior version of the sheet, even if only one figure is being amended. The figure or figure number of an amended drawing should not be labeled as "amended." If a drawing figure is to be canceled, the appropriate figure must be removed from the replacement sheet, and where necessary, the remaining figures must be renumbered and appropriate changes made to the brief description of the several views of the drawings for consistency. Additional replacement sheets may be necessary to show the renumbering of the remaining figures. Each drawing sheet submitted after the filing date of an application must be labeled in the top margin as either "Replacement Sheet" or "New Sheet" pursuant to 37 CFR 1.121(d). If the changes are not accepted by the examiner, the applicant will

Art Unit: 1763

be notified and informed of any required corrective action in the next Office action. The objection to the drawings will not be held in abeyance.

## Claim Objections

3. Claims 11, 24 are objected to because of the following informalities: The claims require "which is nonreactive said process gases". Appropriate correction is required.

## Claim Rejections - 35 USC § 102

4. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 5. Claims 1-5, 8-11, 13-17, and 20-23 are rejected under 35 U.S.C. 102(b) as being anticipated by Drage; David J. (US 4,590,042 A). Drage teaches a gas distribution cathode (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25) for plasma (abstract) enhanced deposition of semiconductor materials onto one or more webs ("wafer"; throughout) of substrate ("wafer"; throughout) material comprising: (a) a cathode body (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25); (b) a process gas distribution system (34, 35; Figure 4; column 3; line 65 column4; line 29) integrated within said cathode body (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25) and including process gas outlets (35; Figure 4; column 3; line 65 column4; line 29) which are evenly dispersed on planar surfaces of said cathode body (13; Figure 1; column 2; lines 26-68; column 4; lines 29) which are evenly dispersed on planar surfaces of said cathode body (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25); and (c) one or more gas dispersion

Art Unit: 1763

plates (15; Figure 1; column 2; lines 26-68) covering said gas outlets (35; Figure 4; column 3; line 65 - column4; line 29) so as to prevent direct, line-of-sight travel of process gas from said gas outlets (35; Figure 4; column 3; line 65 - column4; line 29) to a substrate ("wafer"; throughout) upon which semiconductor material is to be deposited, as claimed by claim 1

Page 4

#### Drage further teaches:

- i. The gas distribution cathode (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25) of claim 1, wherein said process gas distribution system (34, 35; Figure 4; column 3; line 65 column4; line 29) includes at least one primary process gas distribution manifold (22; Figure 1,2), as claimed by claim 2
- ii. The gas distribution cathode (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25) of claim 2, wherein said process gas distribution system (34, 35; Figure 4; column 3; line 65 column4; line 29) includes one or more secondary process gas distribution manifolds (21; Figure 1,2) connected to said primary process gas distribution manifold (22; Figure 1,2), as claimed by claim 3
- iii. The gas distribution cathode (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25) of claim 3, wherein said gas outlets (35; Figure 4; column 3; line 65 column4; line 29) are connected to said secondary process gas distribution manifolds (21; Figure 1,2), as claimed by claim 4
- iv. The gas distribution cathode (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25) of claim 1, wherein said gas outlets (35; Figure 4; column 3; line 65 column4; line 29) are evenly positioned across two opposite surfaces of said cathode body (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25), as claimed by claim 5

Art Unit: 1763

- v. The gas distribution cathode (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25) of claim 1, further including a spent gas evacuation system (37, 42, 41, and 31; Figure 4), as claimed by claim 8
- vi. The gas distribution cathode (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25) of claim 8, wherein said spent gas evacuation system (37, 42, 41, and 31; Figure 4) includes spent gas inlets (37; Figure 4) evenly positioned along at least one peripheral edge of said cathode body (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25), as claimed by claim 9
- vii. The gas distribution cathode (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25) of claim 9, wherein said spent gas inlets (37; Figure 4) are connected to a spent gas collection/removal manifold (23; Figure 2) system, as claimed by claim 10
- viii. The gas distribution cathode (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25) of claim 1, wherein said cathode body (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25), said process gas outlets (35; Figure 4; column 3; line 65 column4; line 29) and said gas dispersion plates (15; Figure 1; column 2; lines 26-68) are formed from a metal (column 5; lines 29-35) or metallic alloy which is nonreactive said process gases, as claimed by claim 11 Applicant's claim requirement of "nonreactive said process gases" is a claim requirement of intended use. Further, it has been held that claim language that simply specifies an intended use or field of use for the invention generally will not limit the scope of a claim (Walter, 618 F.2d at 769, 205 USPQ at 409; MPEP 2106). Additionally, in apparatus claims, intended use must result in a structural difference between the claimed invention and the prior art in order to patentably

Application/Control Number: 10/043,010 Page 6

Art Unit: 1763

distinguish the claimed invention from the prior art. If the prior art structure is capable of performing the intended use, then it meets the claim (In re Casey,152 USPQ 235 (CCPA 1967); In re Otto, 136 USPO 458, 459 (CCPA 1963); MPEP2111.02).

- A deposition chamber (volume confined by 14; Figure 1) for the plasma (abstract) ix. enhanced deposition of semiconductor materials onto one or more webs ("wafer"; throughout) of substrate ("wafer"; throughout) material, said chamber (volume confined by 14: Figure 1) including: a gas distribution cathode (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25) comprising: (a) a cathode body (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25); (b) a process gas distribution system (34, 35; Figure 4; column 3; line 65 - column4; line 29) integrated within said cathode body (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25) and including process gas outlets (35; Figure 4; column 3; line 65 - column4; line 29) which are evenly dispersed on planar surfaces of said cathode body (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25); and (c) one or more gas dispersion plates (15; Figure 1; column 2; lines 26-68) covering said gas outlets (35; Figure 4; column 3; line 65 - column 4; line 29) so as to prevent direct, line-of-sight travel of process gas from said gas outlets (35; Figure 4; column 3; line 65 - column4; line 29) to a substrate ("wafer"; throughout) upon which semiconductor material is to be deposited, as claimed by claim 13
- x. The deposition chamber (volume confined by 14; Figure 1) of claim 13, wherein said process gas distribution system (34, 35; Figure 4; column 3; line 65 column4; line 29) includes at least one primary process gas distribution manifold (22; Figure 1,2), as claimed by claim 14

Art Unit: 1763

xi. The deposition chamber (volume confined by 14; Figure 1) of claim 14, wherein said process gas distribution system (34, 35; Figure 4; column 3; line 65 - column4; line 29) includes one or more secondary process gas distribution manifolds (21; Figure 1,2) connected to said primary process gas distribution manifold (22; Figure 1,2), as claimed by claim 15

Page 7

- xii. The deposition chamber (volume confined by 14; Figure 1) of claim 15, wherein said gas outlets (35; Figure 4; column 3; line 65 column4; line 29) are connected to said secondary process gas distribution manifolds (21; Figure 1,2), as claimed by claim 16
- xiii. The deposition chamber (volume confined by 14; Figure 1) of claim 13, wherein said gas outlets (35; Figure 4; column 3; line 65 column4; line 29) are evenly positioned across two opposite surfaces of said cathode body (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25), as claimed by claim 17
- xiv. The deposition chamber (volume confined by 14; Figure 1) of claim 13, wherein said cathode (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25) further including a spent gas evacuation system (37, 42, 41, and 31; Figure 4), as claimed by claim 20
- xv. The deposition chamber (volume confined by 14; Figure 1) of claim 20, wherein said spent gas evacuation system (37, 42, 41, and 31; Figure 4) includes spent gas inlets (37; Figure 4) evenly positioned along at least one peripheral edge of said cathode body (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25), as claimed by claim 21
- xvi. The deposition chamber (volume confined by 14; Figure 1) of claim 9, wherein said spent gas inlets (37; Figure 4) are connected to a spent gas collection/removal manifold (23; Figure 2) system, as claimed by claim 22

Application/Control Number: 10/043,010 Page 8

Art Unit: 1763

xvii. The deposition chamber (volume confined by 14; Figure 1) of claim 13, wherein said cathode body (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25), said process gas outlets (35; Figure 4; column 3; line 65 - column4; line 29) and said gas dispersion plates (15; Figure 1; column 2; lines 26-68) are formed from a metal (column 5; lines 29-35) or metallic alloy which is nonreactive said process gases, as claimed by claim 23

## Claim Rejections - 35 USC § 103

- 6. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 7. Claims 6, 7, 12, 18, 19, and 24 are rejected under 35 U.S.C. 103(a) as being unpatentable over Drage; David J. (US 4,590,042 A) in view of Dhindsa; Rajinder et al (US 6,786,175 B2). Drage is discussed above. Drage does not teach:
  - i. The gas distribution cathode (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25) of claim 5, wherein said gas outlets (35; Figure 4; column 3; line 65 column 4; line 29) are evenly positioned from 1 to 4 inches apart, as claimed by claim 6
  - ii. The gas distribution cathode (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25) of claim 6, wherein said gas outlets (35; Figure 4; column 3; line 65 column4; line 29) are evenly positioned from 2 to 3 inches apart, as claimed by claim 7
- iii. The gas distribution cathode (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25) of claim 11, wherein said cathode body (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25), said process gas outlets (35; Figure 4; column 3; line 65 column 4; line 29)

Art Unit: 1763

and said gas dispersion plates (15; Figure 1; column 2; lines 26-68) are formed from stainless steel, as claimed by claim 12

- iv. The deposition chamber (volume confined by 14; Figure 1) of claim 17, wherein said gas outlets (35; Figure 4; column 3; line 65 column4; line 29) are evenly positioned from 1 to 4 inches apart, as claimed by claim 18
- v. The deposition chamber (volume confined by 14; Figure 1) of claim 18, wherein said gas outlets (35; Figure 4; column 3; line 65 column4; line 29) are evenly positioned from 2 to 3 inches apart, as claimed by claim 19
- vi. The deposition chamber (volume confined by 14; Figure 1) of claim 23, wherein said cathode body (13; Figure 1; column 2; lines 26-68; column 4; lines 17-25), said process gas outlets (35; Figure 4; column 3; line 65 column4; line 29) and said gas dispersion plates (15; Figure 1; column 2; lines 26-68) are formed from stainless steel, as claimed by claim 24

Dhindsa teaches a stainless steel cathode showerhead (310; Figure 3) for plasma operations (column 8; lines 14-33) including process gas distribution holes (354; Figure 3) with optimal spacing as taught by Dhindsa.

It would have been obvious to one of ordinary skill in the art at the time the invention was made for Drage to use stainless steel material for his Drage's dispersion plates (15; Figure 1; column 2; lines 26-68) and for Drage to optimize the dimension between Drange's gas outlets (35; Figure 4; column 3; line 65 - column 4; line 29) as taught by Dhindsa.

Motivation for Drage to use stainless steel material for his Drage's dispersion plates (15; Figure 1; column 2; lines 26-68) and for Drage to optimize the dimension between Drange's gas outlets

Art Unit: 1763

(35; Figure 4; column 3; line 65 - column4; line 29) as taught by Dhindsa is to enhance transfer

Page 10

heat through Drange's dispersion plates as taught by Dhindsa (column 8; lines 14-33) and to

optimize the gas flow of Drange's process as taught by Dhindsa (column6; lines 15-30). Further,

it is well established that changes in apparatus dimensions are within the level of ordinary skill in

the art.(Gardner v. TEC Systems, Inc., 725 F.2d 1338, 220 USPQ 777 (Fed. Cir. 1984), cert.

denied, 469 U.S. 830, 225 USPQ 232 (1984); In re Rose, 220 F.2d 459, 105 USPQ 237 (CCPA

1955); In re Rinehart, 531 F.2d 1048, 189 USPQ 143 (CCPA 1976); See MPEP 2144.04)

#### Conclusion

8. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure:

US 20010027026 A1

US 6475563 B2

US 6432831 B1

US 6245192 B1

US 6189485 B1

US 6161500 A

US 6148761 A

US 6109209 A

US 5919332 A

US 5900103 A

US 5792261 A

US 5766364 A

Page 11

Art Unit: 1763

US 5580822 A

US 5567267 A

US 5480678 A

US 5010842 A

US 4820371 A

US 4595484 A

US 4209357 A

9. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Examiner Rudy Zervigon whose telephone number is (571) 272.1442. The examiner can normally be reached on a Monday through Thursday schedule from 8am through 7pm. The official fax phone number for the 1763 art unit is (703) 872-9306. Any Inquiry of a general nature or relating to the status of this application or proceeding should be directed to the Chemical and Materials Engineering art unit receptionist at (571) 272-1700. If the examiner can not be reached please contact the examiner's supervisor, Gregory L. Mills, at (571)

272-1439.